Slotted Optical Switch

OPB855



Features:

- Low profile 0.27" (6.86 mm) overall height
- Printed PCBoard mounting
- 0.205" (5.21 mm) wide and 0.220 (5.59 mm) deep slot
- 0.380" (9.65 mm) lead spacing
- Opaque plastic housing

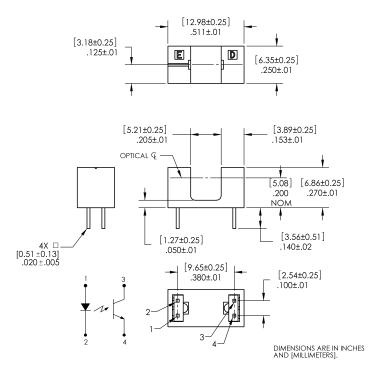


Description:

The OPB855 slotted optical switch consists of an infrared emitting diode and a NPN silicon phototransistor, mounted on opposite sides of a 0.205" (5.21 mm) wide slot in an inexpensive plastic housing. Switching of the phototransistor occurs whenever an opaque object passes through the slot.

Applications:

- Non-contact interruptive object sensing
- Assembly line automation
- Machine automation
- Equipment security
- Machine safety



Pin#	Description
1	Anode
2	Cathode
3	Collector
4	Emitter



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Electrical Specifications

Absolute Maximum Ratings (T_A=25°C unless otherwise noted)

Storage & Operating Temperature Range	-40°C to +85° C
Lead Soldering Temperature [1/16 inch (1.6mm) from the case for 5 sec. with soldering iron] ⁽¹⁾	260° C

Input Diode (See OP140 for additional information)

Forward DC Current	50 mA
Peak Forward Current (1 μs pulse width, 300 pps)	1 A
Reverse DC Voltage	2 V
Power Dissipation ⁽²⁾	100 mW

Output Phototransistor (See OP550 for additional information)

Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5 V
Collector DC Current	30 mA
Power Dissipation ⁽²⁾	100 mW

Electrical Characteristics (T_A = 25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS				
Input Diode										
V _F	Forward Voltage	-	1.30	1.80	V	I _F = 20 mA				
I _R	Reverse Current	-	1	100	μΑ	V _R = 2 V				
Output Phototransistor										
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30	-1	-	V	I _C = 1 mA				
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5	1	-	V	I _E = 100 μA				
I _{CEO}	Collector-Emitter Dark Current	-	1	100	nA	$V_{CE} = 10 \text{ V}, I_F = 0, E_E = 0$				
Combined										
V _{CE(SAT)}	Collector-Emitter Saturation Voltage	-	-	0.4	V	I _C = 400 μA, I _F = 20 mA				

20.0

mA

Notes:

 $I_{C(ON)}$

(1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.

1.50

(2) Derate linearly 1.67 mW/°C above 25 ° C.

On-State Collector Current

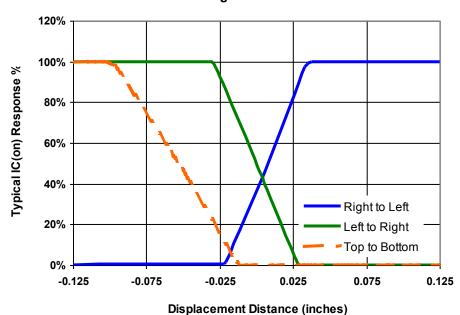
- (3) Methanol or isopropanol are recommended as cleaning agents. Plastic housing is soluble in chlorinated hydrocarbons and ketones.
- (4) All parameters tested using pulse technique.

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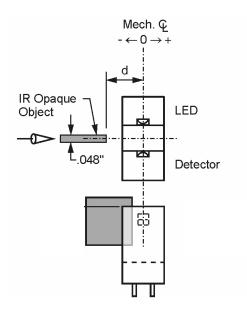
 V_{CE} = 5 V, I_F = 20 mA



OPB855 - Flag in Middle of Slot



Test Schematic



Mouser Electronics

Authorized Distributor

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TT Electronics:
OPB855